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Structure of rare-earth chalcogenide glasses by neutron and x-ray diffraction

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Abstract

The method of neutron diffraction with isomorphic substitution was used to measure the structure of the rare-earth chalcogenide glasses \((R_2X_3)_0.05(Ga_2X_3)_{0.33}(GeX_2)_{0.60}\) with \(R = La\) or \(Ce\) and \(X = S\) or \(Se\). X-ray diffraction was also used to measure the structure of the sulphide glass. The results are consistent with networks that are built from \(Ge\) and \(Ga\) tetrahedra, and give \(R–S\) and \(R–Se\) coordination numbers of 8.0(2) and 8.5(4), respectively. The minimum nearest-neighbour \(R–R\) distance associated with rare-earth clustering is discussed.

Keywords: glass structure, neutron diffraction, x-ray diffraction, rare-earth clustering

(Some figures may appear in colour only in the online journal)

1. Introduction

Many of the trivalent rare-earth ions exhibit intra-\(4f\) shell luminescence that can be exploited to make photonic glasses for, e.g. fibre amplifiers and lasers that operate at wavelengths compatible with fibre communications technology [1–3]. Here, the luminescence of the material will depend, e.g. on the solubility of rare-earth ions in the glass, and on the tendency of rare-earth ions to cluster within their matrix material. The latter leads to a non-uniform distribution of rare-earth ions that can limit the fluorescence lifetime, or lead to the formation of rare-earth compounds that are optically inactive. The luminescence can also be affected by multiphonon relaxation, wherein the probability of non-radiative channels is increased if the phonon energies of the host glass are close to gaps in energy between the \(4f\) electron states of a rare-earth ion. It is therefore desirable to develop glassy materials in which the rare-earth ions are uniformly distributed within a glass matrix having appropriately small phonon energies and low transmission losses at the optical wavelengths of interest.

Chalcogenide glasses, containing one or more of the chalcogen elements (S, Se, Te), have photonic applications that range from digital memory storage to thermal imaging and infrared transmitting media [4–6]. They are also ideal hosts for luminescent rare-earth ions because their maximum phonon energies (e.g. \(\sim 460\) cm\(^{-1}\) for Ge–Ga–S versus \(\sim 340\) cm\(^{-1}\) for Ge–Ga–Se glasses in which the rare-earth solubility is high [7, 8]) are generally small as compared to silica (\(\sim 1100\) cm\(^{-1}\)) and fluoride glasses (\(\sim 400–650\) cm\(^{-1}\)) [3, 4, 9], although it is important to avoid an introduction of the vibrational bands associated with impurities to the phonon density of states [9–13]. The high refractive index of these materials (>2.1) helps to increase the cross section for stimulated emission [14, 15]. Even though rare-earth ions are barely soluble in the binary Ge–S system [10], germanium sulphide based
glasses have attracted much attention because of their transparency in the visible spectrum. Here, the rare-earth solubility can be enhanced by making multicomponent glasses such as $R_2S_3-GaS_3-GeS_2$ [7, 16–21], in which the ability of Ga to form negatively charged $GaS_4$ tetrahedra helps to balance the positive charge on rare-earth ions. The incorporation of Ga also has a tendency to reduce rare-earth clustering [22–24]. This reduction will either (i) increase the fluorescence lifetime if all of the rare-earth ions initially form a single population of clustered species, or (ii) increase the fluorescence intensity corresponding to the longer fluorescence lifetime if the rare-earth ions initially form two populations of clustered versus dispersed species. Accordingly, there have been many investigations to characterise the physico-chemical, optical and luminescent properties of $R_2S_3-GaS_3-GeS_2$ glasses to explore their potential for use in, e.g. optoelectronic devices [7, 11, 13, 15–18, 20, 21, 23, 25–42]. There have been comparatively few investigations of the corresponding selenide or mixed sulphide/selenide glasses [9, 40–48].

In this paper, the method of neutron diffraction with isomorphous substitution (NDIS) of the rare-earth element [49–54] was employed to measure the structure of the rare-earth glasses $(R_2X_3)_{0.07}(Ga_2X_3)_{0.33}(GeX_2)_{0.60}$, with $R = La$ or Ce and $X = S$ or Se. X-ray diffraction was also used to measure the structure of the sulphide glass. The aim is to provide a point of comparison for the effect of different chalcogens on the glass structure. The regions of glass formation in ternary $R_2S_3-GaS_3-GeS_2$ systems containing large rare-earth ions are described in [16, 18, 20, 21]. The composition chosen for study contains a relatively large atomic fraction of the rare earth species $c_R = 0.0368$ which is necessary for an application of the NDIS method. Here, the assumption is made that the 4f electrons of La$^{3+}$ and Ce$^{3+}$, which characterise the difference between their electronic configurations, are sufficiently removed from the valence shell that the cations share a common structural chemistry and form isostructural compounds [1, 55]. This premise is supported by the similarity between the ionic radii of these trivalent cations (1.16 versus 1.14 Å for eightfold coordinated cations) [56] and the similarity between the Pettifor chemical parameters for La and Ce (0.705 versus 0.7025) [57]. There is a significant difference, however, between the neutron scattering lengths of La and Ce that will lead to a contrast between the measured neutron diffraction patterns for isostructural glasses containing one or other of these elements. In this way, it is possible to measure difference functions that separate, essentially, the $R-R$ and $R-\mu$ pair-correlation functions from the $\mu-\mu'$ pair-correlation functions, where $\mu$ (or $\mu'$) denotes a matrix atom, i.e. Ge, Ga or X. This simplification in the structural complexity associated with a single diffraction pattern enables the NDIS method to provide the type of site-specific structural information that is required in the development of realistic structural models, a prerequisite for establishing the structure-function relationships for rare-earth chalcogenide glasses.

The paper is organised as follows. The essential diffraction theory is given in section 2, and the experimental methodology is described in section 3. The results for the sulphide and selenide glasses are presented in section 4, and are discussed in section 5 by reference to (i) the structural models that have been proposed and (ii) the presence of rare-earth clustering. Conclusions are drawn in section 6.

2. Theory

In an x-ray or neutron diffraction experiment on $(R_2X_3)_{0.07}(Ga_2X_3)_{0.33}(GeX_2)_{0.60}$, the desired structural information is described by the total structure factor [58]

$$F(Q) = \sum_{\alpha=1}^{n} \sum_{\beta=1}^{n} c_\alpha c_\beta f_\alpha(Q)f^*_\beta(Q)[S_{\alpha\beta}(Q) - 1],$$

where $\alpha$ and $\beta$ denote the chemical species, $n = 4$ is the number of different chemical species, $c_\alpha$ represents the atomic fraction of chemical species $\alpha$, $f_\alpha(Q)$ and $f^*_\beta(Q)$ are the scattering length (or atomic form factor) and its complex conjugate for chemical species $\alpha$, respectively, $S_{\alpha\beta}(Q)$ is a Faber–Ziman [59] partial structure factor, and $Q$ is the magnitude of the scattering vector. $S_{\alpha\beta}(Q)$ is related to the partial pair-distribution function $g_{\alpha\beta}(r)$ by the Fourier transform relation

$$g_{\alpha\beta}(r) - 1 = \frac{1}{2\pi^2 n_0 r} \int_0^\infty dQ \frac{F(Q)}{Q [S_{\alpha\beta}(Q) - 1]} \sin(Qr),$$

where $n_0$ is the atomic number density and $r$ is a distance in real space. The mean coordination number of atoms of type $\beta$, contained in a volume defined by two concentric spheres of radii $r_i$ and $r_j$ centred on an atom of type $\alpha$, is given by

$$n^2 = 4\pi n_0 c_\beta \int_{r_i}^{r_j} dr r^2 g_{\alpha\beta}(r).$$

The scattering lengths are independent of $Q$ for the case of neutron diffraction, but not for the case of x-ray diffraction. In order to compensate for this $Q$ dependence, the total structure factor can be rewritten as

$$S(Q) = 1 + \frac{F(Q)}{\langle F(Q) \rangle^2},$$

where $\langle F(Q) \rangle = \sum_\alpha c_\alpha f_\alpha(Q)$ is the mean scattering length. The corresponding real-space information is contained in the total pair-distribution function

$$G(r) = 1 + \frac{1}{2\pi^2 n_0 r} \int_0^\infty dQ \frac{Q[S(Q) - 1]}{\sin(Qr)}.$$

In x-ray diffraction experiments, the normalisation defined by equation (4) has the advantage that it allows for a better resolution of the peaks in $G(r)$.

Consider a neutron diffraction experiment performed on two samples of $R$–Ge–Ga–X glass that are identical in every respect, except that $R$ represents La, a 50:50 mixture of La and Ce, or Ce. Let the corresponding total structure factors be denoted by $^{La}F(Q)$, $^{Max}F(Q)$ and $^{Ce}F(Q)$, respectively, where $b_{La} > b_{Max} > b_{Ce}$. Then, if the rare-earth elements can be regarded as isomorphic, the contribution to a total structure factor from the $\mu-\mu'$ pair-correlation functions can be eliminated by taking a difference function such as
\[ \Delta F^{(1)}_R(Q) \equiv F(Q) - C F(Q) \]
\[ = 2\bar{c}_Q c_b b_{(b_{La} - b_{Ce})} [S_{bb}(Q) - 1] + 2\bar{c}_Q c_b b_{(b_{La} - b_{Ce})} [S_{bc}(Q) - 1] + 2\bar{c}_Q c_b b_{(b_{La} - b_{Ce})} [S_{bc}(Q) - 1] + \bar{c}_Q^2 b_{(b_{La} - b_{Ce})} [S_{bb}(Q) - 1]. \]

Related difference functions are defined by \( \Delta F^{(2)}_R(Q) \equiv F(Q) - \text{Max} F(Q) \) and \( \Delta F^{(3)}_R(Q) \equiv \text{Max} F(Q) - C F(Q). \) Similarly, it is possible to eliminate the \( \mu-\mu \) pair-correlations by taking a difference function such as
\[ \Delta F^{(1)}_{\mu}(Q) \equiv F(Q) - [b_{La}/(b_{La} - b_{Ce})] \Delta F^{(1)}_R(Q) \]
\[ = [b_{La} c_Q F(Q) - b_{Ce} F(Q)] / (b_{La} - b_{Ce}) = \Delta F^{(1)}_{\mu}(Q) - \bar{c}_Q^2 b_{La} b_{Ce} [S_{bb}(Q) - 1], \]

where \( \Delta F^{(1)}_{\mu}(Q) \equiv \sum_{i=1}^{n} \sum_{j=1}^{m} \delta_{ij} r_{ij} b_{ij} b_{ij} [S_{ij}(Q) - 1] \) contains only the \( \mu-\mu \) pair-correlation functions and \( m = 3 \) is the total number of matrix species. Related difference functions are defined by \( \Delta F^{(2)}_{\mu}(Q) \equiv F(Q) - [b_{La}/(b_{La} - b_{Max})] \Delta F^{(2)}_R(Q) \) and \( \Delta F^{(3)}_{\mu}(Q) \equiv [b_{Max}/(b_{Max} - b_{Ce})] \Delta F^{(3)}_R(Q). \) The coherent neutron scattering lengths are \( b_{La} = 8.24(4) \text{ fm}, \) \( b_{Max} = 6.54(4) \text{ fm}, \) \( b_{Ce} = 4.84(2) \text{ fm}, \) \( b_{Ga} = 7.288(2) \text{ fm}, \) \( b_{Se} = 8.185(20) \text{ fm}, \) \( b_{Sn} = 2.847(1) \text{ fm}, \) and \( b_{Te} = 7.970(9) \text{ fm}. \) The ratio of the \( R-R \) weighting factor \( c_Q^2 b_{La} b_{Ce} \) to the weighting factors for the \( \mu-\mu \) pair-correlations is small (e.g. in the case of \( \Delta F^{(1)}_{\mu}(Q), 0.285\% \) for the sulphide glass versus 0.087\% for the selinide glass), i.e. the \( \Delta F^{(1)}_{\mu}(Q) \) functions are dominated by the \( \mu-\mu \) pair-correlation functions.

The real-space functions corresponding to \( \Delta F^{(1)}_{\mu}(Q) \) and \( \Delta F^{(1)}_{\mu}(Q) \) (\( i = 1, 2 \) or 3) are obtained by Fourier transformation, and are denoted by \( G^{(1)}_{\mu}(r) \) and \( G^{(1)}_{\mu}(r), \) respectively. The equations for, e.g. \( G^{(1)}_{\mu}(r) \) and \( G^{(1)}_{\mu}(r) \) are obtained from equations (6) and (7), respectively, by replacing each \( S_{bb}(Q) \) function by the corresponding partial pair-distribution function \( g_{\delta_{bb}}(r). \)

### 3. Experimental method

#### 3.1. Glass synthesis and characterisation

Each sulphide glass was prepared in 3 g batches by loading high-purity elemental Ge (Aldrich, 99.99999\%), Ga (Aldrich, 99.9999\%), and S (Alfa Aesar Puratronic\®, 99.9995\%) along with LaS3 (Alfa Aesar, 99.9\%) or CeS3 (Alfa Aesar, 99.9\%), with the correct mass ratio, into a silica ampoule of 5 mm inner diameter and 1 mm wall thickness that had been etched using a 40 wt\% solution of hydrofluoric acid, rinsed using distilled water then high-purity acetone, and baked dry under vacuum at 750 °C for 2h. The ampoule was loaded in a high-purity argon-filled glove box, isolated using a Young’s tap, and then transferred to a vacuum line where it was sealed under a pressure of 10−5 Torr. The sealed ampoule was placed in a rocking furnace, which was heated at a rate of 1 °C min−1 from ambient to a temperature \( T = 1100 \) °C, dwelling for 4h each at \( T = 112 \) °C, \( T = 445 \) °C and \( T = 937 \) °C, near to the melting and boiling points of S, and the melting point of Ge, respectively. The highest temperature was maintained for \( \geq 24 \) h before the rocking motion was stopped, the furnace was placed vertically for 12h to let the melt collect at the bottom of the ampoule, and the ampoule was then dropped into an ice/water mixture. The selenide glasses were prepared similarly, except that Se (Aldrich, 99.9999\%) and either La (Alpha Aesar, 99.9\%) or Ce (Alpha Aesar, 99.9\%) metal were used as starting ingredients, the lowest dwell temperatures were set at \( T = 221 \) °C and \( T = 685 \) °C, corresponding to the melting and boiling points of Se, and the upper dwell temperature was set to either \( T = 920 \) °C or \( T = 795 \) °C, corresponding to the melting temperatures of elemental La and Ce, respectively. Each sample was broken out of its ampoule inside a high-purity argon-filled glove box.

The density of each glass was measured using a Quantachrome helium gas pycnometer (table 1). The sulphide glasses were investigated by simultaneous differential scanning calorimetry and thermal gravimetric analysis using a TA Instruments SDT Q600 machine operated with oxygen free nitrogen gas at a scan rate of 10.00 °C min−1. The samples started to lose mass in the vicinity of the crystallisation exotherm, i.e. at a temperature greater than the glass transition temperature \( T_g \) (table 1). For glassy (La2Se3)0.07(Ga2Se3)0.33 (GeSe2)0.60, \( T_g \) was taken from the reversible heat flow measured by modulated differential scanning calorimetry using a TA Instruments Q100 machine operated with oxygen free nitrogen gas at a scan rate of 3 °C min−1 and modulation rate of ±1 °C min−1.

#### 3.2. High energy x-ray diffraction experiments

High energy x-ray diffraction experiments were performed on three \( (R_2S_3)_{0.07}(Ga_2S_3)_{0.33}(GeSe_2)_{0.60} \) glasses, with \( R = \text{La}, \text{Mix} \) or Ce, using beamline ID15B at the ESRF, France. Finely powdered samples were sealed between two layers of kapton 77–80 tape, giving a slab geometry with a sample thickness of 1 mm. The incident x-ray energy was 88.76 keV and the diffraction patterns were measured at room temperature for each sample in its container, an empty kapton container, and the empty instrument. The program FIT2D [61, 62] was used to correct each data set for geometrical effects and polarisation of the incident beam.

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**Table 1.** The measured mass density \( \rho \), atomic number density \( n_0 \) and glass transition temperature \( T_g \) for \( (R_2S_3)_{0.07}(Ga_2S_3)_{0.33}(GeSe_2)_{0.60} \) glasses.

<table>
<thead>
<tr>
<th>( R )</th>
<th>( X )</th>
<th>( \rho ) (g cm−3)</th>
<th>( n_0 ) (Å−3)</th>
<th>( T_g ) (midpoint) (°C)</th>
</tr>
</thead>
<tbody>
<tr>
<td>La</td>
<td>S</td>
<td>3.26(1)</td>
<td>0.040(1)</td>
<td>430(2)</td>
</tr>
<tr>
<td>Mix</td>
<td>S</td>
<td>3.27(1)</td>
<td>0.040(1)</td>
<td>444(5)</td>
</tr>
<tr>
<td>Ce</td>
<td>S</td>
<td>3.24(1)</td>
<td>0.040(1)</td>
<td>446(2)</td>
</tr>
<tr>
<td>La</td>
<td>Se</td>
<td>4.79(1)</td>
<td>0.037(1)</td>
<td>403(2)</td>
</tr>
<tr>
<td>Ce</td>
<td>Se</td>
<td>4.79(1)</td>
<td>0.037(1)</td>
<td>—</td>
</tr>
</tbody>
</table>
before integrating over the Debye–Schererr cones to produce a one-dimensional diffraction pattern, which was normalised to the incident beam intensity. The data sets for each sample were then corrected for background and container scattering, taking attenuation effects into account, and were scaled to fit the sum of the Compton scattering and self-scattering contributions at high $Q$ values, where neutral atom form factors $f_\alpha(Q)$ were taken from [64]. The Compton and self-scattering contributions were then subtracted to obtain $F_X(Q)$, which was converted to the total x-ray structure factor $S_X(Q)$ using equation (4).

### 3.3. Neutron diffraction experiments

Neutron diffraction experiments were performed on three $(R_2S_3)_{0.07}(Ga_2S_3)_{0.33}(GeS_2)_{0.60}$ glasses, with $R =$ La, Mix or Ce, using the GEM instrument [65] at the ISIS facility. Powdered samples (each of mass $\sim$6 g) were held in a cylindrical vanadium container of 6.8 mm inner diameter and 0.1 mm wall thickness. Diffraction patterns were taken for each sample in its vanadium container, the empty container, the empty instrument, and a cylindrical vanadium rod of diameter 8.36 mm at ambient temperature ($\approx 25$ °C). The intensities for each detector group were saved at regular intervals, and no deviation between these intensities was observed outside the statistical variation, which verified the diffractometer stability [66]. The data sets were processed using the GUDRUN analysis program [67], and the data sets for the Ce and Mix samples were also corrected for the paramagnetic scattering from Ce$^{3+}$ by using the procedure described in [49]. Self-consistency checks were performed to ensure that (i) a measured neutron total structure factor $S_N(Q)$ obeys the sum-rule relation

$$\int_0^\infty dQ \, Q^2 [S_N(Q) - 1] = -2\pi^2 n_0$$

which follows from equation (5) by taking the limit as $r \to 0$; (ii) the low-$r$ features in the corresponding $G_X(r)$ function oscillate about their theoretical $G_X(r \to 0) = 0$ limit; and (iii) the back Fourier transform of $G_X(r)$, after the low-$r$ oscillations are set to $G_X(r \to 0) = 0$, is in good overall agreement with the measured $S_N(Q)$ function [68].

Neutron diffraction experiments were also performed on two $(R_2S_3)_{0.07}(Ga_2S_3)_{0.33}(GeS_2)_{0.60}$ glasses, with $R =$ La or Ce, using the GLAD instrument [69] at the intense pulsed neutron source (IPNS). Powdered samples (each of mass $\sim$12 g) were held in cylindrical vanadium containers of 4.64 mm inner diameter and 0.13 mm wall thickness. The experimental procedure followed that described for GEM, except that a cylindrical vanadium rod of diameter 9.5 mm was used for calibration purposes, and the data sets were processed using the ISAW analysis program [70].

### 4. Results

#### 4.1. Sulphide glasses

The x-ray total structure factors $S_X(Q)$ measured for the rare earth sulphide glasses (figure 1(a)) have a first sharp diffraction peak (FSDP) at 1.08(2) Å$^{-1}$ (table 2) that is indicative of ordering on an intermediate length scale [71]. The atomic form factors for the rare-earth ions are similar because the atomic numbers for La and Ce are $Z_{La} = 57$ and $Z_{Ce} = 58$, respectively. Thus, the close similarity between the measured $S_X(Q)$ functions (figure 1(b)) is indicative of structural isomorphism.

The first peak in $G_X(r)$ at 2.25(2) Å (figure 2) is attributed to a superposition of nearest neighbour Ga–S and Ge–S pair-correlations, and its position compares with Ga–S and Ge–S intra-tetrahedral bond distances of 2.19 $\leq r_{GaS}(Å) \leq 2.37$ in crystalline Ga$_2$S$_3$ [72–74] versus 2.17 $\leq r_{GeS}(Å) \leq 2.28$ in crystalline GeS$_2$ [75–77]. The atomic form factors for Ga and Ge are similar because their atomic numbers are similar at $Z_{Ga} = 31$ and $Z_{Ge} = 32$. Hence, by converting $S_X(Q)$ to $F_X(Q)$ and dividing by $c_{GeS} f_r^{GeS}(Q) f_r^{Ge}(Q) + f_r^{Ge}(Q) f_r^{GeS}(Q)$, the Q-dependent weighting factors on the Ga–S and Ge–S partial structure factors are more-or-less removed. In this way [78], the Fourier transform of the resultant $Q$-space function enables the Ga–S and Ge–S coordination numbers to be extracted by direct integration of the first peak. If it is assumed that $n_{Ge}^{Ga} = 4$, then $n_{Ge}^{Ga} = 4.1(1)$ is obtained by integrating over the range 1.90 $\leq r(Å) \leq 2.64$ (table 2). The results are therefore consistent with the formation of both GaS$_2$ and GeS$_2$ tetrahedra. The second peak in $G_X(r)$ at 3.03(3) Å is attributed to nearest-neighbour R–S pair-correlations by comparison with the bond lengths found in crystalline R–Ga–Ge–S, R–Ga–S and R–Ge–S materials with $R =$ La or Ce (table 3). By converting

![Figure 1.](image-url)
are shown in figure 6. The first peak in
1.05(2) 2.22(2) 3.67(2) 2.24(2) 4.0(1)

is obtained by integrating over the
1.03(2) 2.06(2) 3.50(2) 2.38(2) 4.0(1)

obtained by Fourier transforming the
1.07(2) 2.19(2) 3.68(2) 2.25(2) 3.9(1) 3.03(3) 8.4(2) 3.66(5)

, dividing by
1.03(2) 2.08(2) 3.50(2) 2.38(2) 3.9(1) 3.09(3) 8.1(9) 3.82(5)

and
1.05(2) 2.19(2) 3.68(2) 2.24(2) 3.9(1) 2.97(3) 11.8(9) 3.62(5)

S S
1.05(2) 2.18(2) 3.68(2) 2.25(2) 3.9(1) 3.01(3) 8.8(9) 3.63(5)

, and the coordination
1.03(2) 2.05(2) 3.50(2) 2.37(2) 4.0(1) — — 3.87(5) —

number
1.07(2) 2.19(2) 3.68(2) 2.25(2) 3.9(1) 2.97(3) 11.8(9) 3.62(5) —

,(figure 2) as compared to
1.09(2) 2.46(2) — — — 3.11(3) 8.5(4) 3.84(5) 4.75(5)

are shown in
1.05(2) 2.19(2) 3.71(2) 2.25(2) 4.1(1)(1) 3.03(3) 8.4(2) 3.66(5) —

and
1.08(2) 2.19(2) 3.71(2) 2.25(2) 4.1(1) 3.03(3) 8.4(2) 3.66(5) —

are listed, together with the coordination number
1.08(2) 2.19(2) 3.71(2) 2.25(2) 4.1(1) 3.03(3) 8.4(2) 3.66(5)

X
1.05(2) 2.19(2) 3.68(2) 2.25(2) 3.9(1) 2.97(3) 11.8(9) 3.62(5) —

First three peak positions
1.05(2) 2.23(2) 3.67(2) 2.25(2) 4.1(1) — — 3.61(5) —

are measured for the
1.03(2) 2.06(2) 3.50(2) 2.38(2) 3.9(1) 3.14(3) 9.8(9) 3.85(5) —

1.05(2) 2.19(2) 3.68(2) 2.24(2) 3.9(1) 2.97(3) 11.8(9) 3.62(5) —

S X
1.08(2) 2.19(2) 3.71(2) 2.25(2) 4.1(1) 3.03(3) 8.4(2) 3.66(5) —

and
1.03(2) 2.06(2) 3.50(2) 2.38(2) 3.9(1) 3.14(3) 9.8(9) 3.85(5) —

rare-earth sulphide glasses are shown in figure 3, and the corre-
1.05(2) 1.95(2)

sponding total pair-distribution functions
1.05(2) 1.95(2)

Figure 2. The x-ray total pair-distribution functions
1.05(2) 1.95(2)

La G (r) + 3
1.05(2) 1.95(2)

Me G (r) + 3
1.05(2) 1.95(2)

Ce G (r)
1.05(2) 1.95(2)

are shown in
1.05(2) 1.95(2)

La G (r)
1.05(2) 1.95(2)

Me G (r)
1.05(2) 1.95(2)

Ce G (r)
1.05(2) 1.95(2)

Table 2. First three peak positions Q1–Q3 in the reciprocal-space functions measured for glassy (R2X3)0.60(Ga2X3)0.33(GeX3)0.66, where R represents La, Ce or Mix, and X represents S or Se. The peak positions r1–r2 in the corresponding real-space functions are also listed, together with the coordination number nX obtained from the area under the peak at r1 by assuming that nGa = 4, and the coordination number nR obtained from the area under the peak at r2.

1.05(2) 1.95(2)

Table 2.
First three peak positions Q1–Q3 in the reciprocal-space functions measured for glassy (R2X3)0.60(Ga2X3)0.33(GeX3)0.66, where R represents La, Ce or Mix, and X represents S or Se. The peak positions r1–r2 in the corresponding real-space functions are also listed, together with the coordination number nX obtained from the area under the peak at r1 by assuming that nGa = 4, and the coordination number nR obtained from the area under the peak at r2.

Figure 2. The x-ray total pair-distribution functions La G (r), Me G (r), and Ce G (r) obtained by Fourier transforming the S X(Q) functions shown in figure 1 after truncating at a maximum scattering vector Qmax = 18 Å−1. The broken (red) curves indicate the extent of the unphysical low-r oscillations.
its integration over the range $2.76 \leq r(\text{Å}) \leq 3.50$ gives a mean coordination number $n_{R}^{S} = 8.0(2)$. This value is smaller than obtained from the second peak in $G_{X}(r)$ (table 2), which is consistent with a contribution to the latter from $\mu-\mu'$ pair-correlations. The second peak in $\Delta G_{X}^{\mu}(r)$ at $\approx 3.86$ Å is attributed to a superposition of $R$–$Ge$ and $R$–$Ga$ pair-correlations (table 3). The third peak in $\Delta G_{X}^{\mu}(r)$ at $\approx 4.65$ Å is expected to have a contribution from nearest neighbour $R$–$R$ pair-correlations on the basis that the minimum $R$–$R$ distance is $r_{RR}^{\min}\approx 4.82$–$4.87$ Å for the crystalline sulphides reported in table 3. As in the case of $G_{S}(r)$, the first peak in $\Delta G_{X}^{\mu}(r)$ at $2.24(2)$ Å is attributed to a superposition of Ga–S and Ge–S pair-correlations and, if it is assumed that $n_{Ga}^{S} = 4$, a coordination number $n_{Ge}^{S} = 4.1(1)$ is obtained by integrating over the range $2.02 \leq r(\text{Å}) \leq 2.64$. The second peak in $\Delta G_{X}^{\mu}(r)$ at $\approx 3.59$ Å overlaps with the first peak in $\Delta G_{X}^{\mu}(r)$ at $\approx 3.09$ Å, which confirms a contribution from $\mu-\mu'$ pair-correlations to the second peak in $G_{X}(r)$.

It was not possible to extract reliably the $R$–$R$ partial structure factor from the measured data sets by using difference function methods [51, 68, 94]. This situation is likely to have originated from the small atomic fraction of the rare-earth ions ($c_{R} = 0.0368$), and the possibility of some residual $\mu-\mu'$ pair-correlations in $\Delta G_{X}^{\mu}(r)$, i.e. the sample compositions may not have matched exactly.

### 4.2. Selenide glasses

The neutron total structure factors $S_{N}(Q)$ measured for the rare-earth selenide glasses are shown in figure 7, and the corresponding total pair-distribution functions $G_{X}(r)$ are shown in

<table>
<thead>
<tr>
<th>Crystal</th>
<th>$n_{Ga}^{S}$</th>
<th>$r_{GaX}$ (Å)</th>
<th>$n_{Ge}^{S}$</th>
<th>$r_{GeX}$ (Å)</th>
<th>$n_{R}^{S}$</th>
<th>$r_{RX}$ (Å)</th>
<th>$r_{RR}^{\min}$ (Å)</th>
<th>$r_{RG}^{\min}$ (Å)</th>
<th>$r_{RR}^{\min}$ (Å)</th>
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<td>La$<em>{2}$Ga$</em>{2}$Ge$<em>{3}$S$</em>{4}$</td>
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<td>2.19–2.26</td>
<td>8</td>
<td>2.93–3.12</td>
<td>3.75</td>
<td>4.45</td>
<td>4.87</td>
<td>[79]</td>
</tr>
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<td>La$<em>{2}$Ge$</em>{5}$O$<em>{3}$Ge$</em>{3}$/Ga$<em>{0.5}$S$</em>{7}$</td>
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<td>2.20–2.25</td>
<td>4</td>
<td>2.20–2.25</td>
<td>8</td>
<td>2.89–3.28</td>
<td>3.57</td>
<td>3.68</td>
<td>4.42</td>
<td>[80]</td>
</tr>
<tr>
<td>LaGaS$_{3}$</td>
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<td>2.09–2.53</td>
<td>—</td>
<td>—</td>
<td>8.3</td>
<td>2.82–3.48</td>
<td>3.50</td>
<td>—</td>
<td>4.33</td>
<td>[81]</td>
</tr>
<tr>
<td>LaGaS$_{3}$</td>
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<td>2.20–3.33</td>
<td>—</td>
<td>—</td>
<td>8</td>
<td>2.81–3.59</td>
<td>3.69</td>
<td>—</td>
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<td>[82]</td>
</tr>
<tr>
<td>La$<em>{2}$Ga$</em>{3.33}$S$_{14}$</td>
<td>4</td>
<td>2.23–2.28</td>
<td>—</td>
<td>—</td>
<td>8</td>
<td>2.85–3.39</td>
<td>3.56</td>
<td>—</td>
<td>4.44</td>
<td>[83]</td>
</tr>
<tr>
<td>Ce$<em>{2}$Ga$</em>{3.33}$S$_{14}$</td>
<td>4</td>
<td>2.23–2.25</td>
<td>—</td>
<td>—</td>
<td>8</td>
<td>2.82–3.38</td>
<td>3.53</td>
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<td>4.41</td>
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<tr>
<td>La$<em>{2}$Ge$</em>{5}$S$_{12}$</td>
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<td>—</td>
<td>4</td>
<td>2.19–2.24</td>
<td>9</td>
<td>2.86–3.74</td>
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<td>3.71</td>
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<td>La$<em>{2}$Ge$</em>{5}$S$_{7}$</td>
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<td>3.76</td>
<td>4.30</td>
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<td>—</td>
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<td>8.5</td>
<td>2.84–3.33</td>
<td>—</td>
<td>3.77</td>
<td>4.32</td>
<td>[87]</td>
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<td>LaGe$<em>{1.25}$S$</em>{7}$</td>
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<td>—</td>
<td>4</td>
<td>2.17–2.22</td>
<td>8</td>
<td>2.85–3.17</td>
<td>—</td>
<td>3.51</td>
<td>4.34</td>
<td>[88]</td>
</tr>
<tr>
<td>La$<em>{2}$Ge$</em>{5}$S$_{12}$</td>
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<td>—</td>
<td>4</td>
<td>2.19–2.25</td>
<td>9</td>
<td>2.86–3.73</td>
<td>—</td>
<td>3.71</td>
<td>4.05</td>
<td>[89]</td>
</tr>
<tr>
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<td>—</td>
<td>4</td>
<td>2.00–2.34</td>
<td>8</td>
<td>2.85–3.46</td>
<td>—</td>
<td>3.64</td>
<td>4.47</td>
<td>[90]</td>
</tr>
<tr>
<td>Ce$<em>{2}$Ge$</em>{5}$S$_{12}$</td>
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<td>—</td>
<td>4</td>
<td>2.19–2.24</td>
<td>9</td>
<td>2.85–3.72</td>
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<td>3.70</td>
<td>4.03</td>
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<td>3.69</td>
<td>4.02</td>
<td>[91]</td>
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<td>—</td>
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<td>3.58</td>
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<td>3.56</td>
<td>4.37</td>
<td>[87]</td>
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<td>2.27–2.31</td>
<td>—</td>
<td>—</td>
<td>8</td>
<td>2.94–3.38</td>
<td>3.63</td>
<td>—</td>
<td>4.54</td>
<td>[83]</td>
</tr>
<tr>
<td>La$<em>{2}$Ga$</em>{1.4}$Se$_{7}$</td>
<td>—</td>
<td>—</td>
<td>4</td>
<td>2.31–2.37</td>
<td>8</td>
<td>3.02–3.27</td>
<td>—</td>
<td>3.69</td>
<td>4.55</td>
<td>[92]</td>
</tr>
<tr>
<td>La$<em>{2}$Ge$</em>{5}$Se$_{14}$</td>
<td>—</td>
<td>—</td>
<td>4</td>
<td>2.27–2.33</td>
<td>8</td>
<td>2.84–2.88</td>
<td>—</td>
<td>3.02–3.35</td>
<td>3.72</td>
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<td>2.32–2.37</td>
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<td>4</td>
<td>2.26–2.31</td>
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<td>2.82–2.86</td>
<td>—</td>
<td>2.99–3.33</td>
<td>3.69</td>
<td>4.56</td>
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<td>—</td>
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<td>2.74–2.76</td>
<td>—</td>
<td>—</td>
<td>—</td>
<td>—</td>
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</tr>
</tbody>
</table>

*Table 3.* The Ga–X, Ge–X and $R$–X coordination numbers $n_{Ga}^{X}$, $n_{Ge}^{X}$ and $n_{R}^{X}$, and corresponding bond distances $r_{GaX}$, $r_{GeX}$ and $r_{RX}$, respectively, in crystalline $R$–Ga–Ge–S, $R$–Ga–X or $R$–Ge–X materials, where $R = La$ or Ce and $X = S$ or Se. In several of these materials, Ga or Ge have both tetrahedral and octahedral coordination environments. Also given are the minimum nearest-neighbour $R$–Ga, $R$–Ge and $R$–R distances $r_{RG}^{\min}$, $r_{GeR}^{\min}$ and $r_{RR}^{\min}$, respectively. More information is available on the crystal structures of the sulphides as compared to the selenides.
The neutron total structure factors $^{14}$Sn(Q), $^{15}$Si(Q), and $^{47}$Sc(Q) for glassy ($R_2S_3)_{0.07}$[(Ga$_2$S$_3)_{0.33}$GeS$_2)_{0.60}$] are shown in figures 9(a) and 10(a), respectively. The vertical (dark grey) bars represent the measured data points with statistical errors, and the solid (red) curves are the back Fourier transforms of the corresponding $G_N(r)$ functions shown in figure 4 after the unphysical low-$r$ oscillations are set to the theoretical $G_N(r \rightarrow 0) = 0$ limit.

The positions of the leading peaks in both reciprocal and real space are listed in table 2. The first peak in $G_N(r)$ at 2.38(2) Å is attributed to a superposition of nearest neighbour Ga–Se and Ge–Se pair-correlations, and its position compares with intra-tetrahedral bond distances of 2.32 ≤ $r_{GaSe}$ (Å) ≤ 2.48 in crystalline Ga$_2$Se$_3$ [95, 96] versus 2.34 ≤ $r_{GeSe}$ (Å) ≤ 2.37 in crystalline GeSe$_2$ [97]. On the assumption that $\tilde{n}_{Ga}^{Se} = 4$, integration of this peak over the range 2.15 ≤ $r(\tilde{A})$ ≤ 2.58 gives $\tilde{n}_{Ge}^{Se} = 3.9(1)$. The results are therefore consistent with the formation of a network containing both GaSe$_4$ and GeSe$_4$ tetrahedra. The second peak in $G_N(r)$ at ≈3.09–3.14 Å is attributed to nearest-neighbour R–Se pair-correlations by comparison with the bond lengths found in crystalline R–Ga–Se and R–Ge–Se materials with $R = $ La or Ce (table 3). The $\tilde{n}_{R}^{Se}$ values obtained by integrating this peak over the range 2.82 ≤ $r(\tilde{A})$ ≤ 3.19 are not, however, identical (table 2), which indicates a contribution to the second peak from $\mu-\mu'$ pair-correlations.

The difference function $\Delta F_R^{(1)}(Q)$ and its Fourier transform $\Delta G_R^{(1)}(r)$ are shown in figures 9(a) and 10(a), respectively. The $\Delta F_R^{(1)}(Q)$ function is relatively noisy, so the data set was truncated at $Q_{\text{max}} = 10$ Å$^{-1}$ to reduce Fourier transform artifacts in $\Delta G_R^{(1)}(r)$. The first and second peaks in $\Delta G_R^{(1)}(r)$ at 3.11(3) and 3.84(5) Å are attributed to the nearest-neighbour R–Se pair-correlations and to a superposition of the $R$–Ga and $R$–Ge pair-correlations, respectively. As compared to $\Delta G_R^{(1)}(r)$ for the corresponding sulphide glass (figure 6(a)), the first peak is higher than the second peak because $b_{Se}/b_{S} = 2.799$. The first peak gives a coordination number $\tilde{n}_{R}^{Se} = 8.5(4)$ by integrating over the range 2.76 ≤ $r(\tilde{A})$ ≤ 3.56 to the first minimum, which compares to $\tilde{n}_{R}^{Se} = 8.9$ for large rare earth ions in related crystalline materials (table 3). This coordination number is different to those found from the $G_N(r)$ functions (table 2), which points to an overlap of the the $R$–Se and $\mu-\mu'$ pair-correlation functions in $G_N(r)$, and to the difficulty in extracting $\tilde{n}_{R}^{Se}$ from the total pair-distribution functions. The third peak in $\Delta G_R^{(1)}(r)$ at 4.75(5) Å is likely to have a contribution from $R$–$R$ pair-correlations on the basis that $r_{RR}^{\text{min}} \approx 4.52–4.59$ Å for the crystalline selenides reported in table 2.

The difference function $\Delta F_R^{(1)}(Q)$ and its Fourier transform $\Delta G_R^{(1)}(r)$ are shown in figures 9(b) and 10(b), respectively. As for the case of $G_N(r)$, the first peak in $\Delta G_R^{(1)}(r)$ at 2.37(2) Å is attributed to a superposition of Ga–Se and Ge–Se pair-distribution functions and, if it is assumed that $\tilde{n}_{Ga}^{Se} = 4$, a coordination number $\tilde{n}_{Ge}^{Se} = 4.0(1)$ is obtained by integrating this peak over the range 2.15 ≤ $r(\tilde{A})$ ≤ 2.64. The glass composition can be re-written as (Ga$_2$Se$_3)_{0.07}$[(Ga$_2$S$_3)_{0.33}$GeS$_2)_{0.60}$] and its Fourier transform is obtained by integrating this peak over the range 2.15 ≤ $r(\tilde{A})$ ≤ 2.64. The glass composition can be re-written as (Ga$_2$Se$_3)_{0.07}$[(Ga$_2$S$_3)_{0.33}$GeS$_2)_{0.60}$].
or

- limits. For clarity of presentation, functions shown in figure 5 after spline fitting the data.

- functions, or with a bond distance

- shown in figure 6, after the unphysical low-

- oscillations. For clarity of presentation, several of the data sets are displaced vertically.

- and Se atoms can also increase their coordination number

- fraction of homopolar bonds in ethane-like units increases, they are bound exclusively to four Se atoms. In response, the

- because the Ga:Se ratio is 1:3/2, i.e. less of the Ga and Ge

- increasing

- may have a contribution from the Ge

- distances in edge-sharing GeSe4 tetrahedra, the peak at 3.87(5) Å may have a contribution from Se–Se pair-correlations, and the low-

- shoulder on this peak at ≃3.6 Å may have a contribution from the Ge–Ge pair-correlations in corner-sharing tetrahedra. In

- formation fine structure (EXAFS) spectroscopy [30, 31]. In the case of glassy (La2S3)0.167(Er2S3)0.083(Ga2S3)0.417(GeS2)0.333, EXAFS investigations at the Ga and Ge K-edges indicate the formation of GaS4 and GeS4 tetrahedra with bond distances of $r_{\text{GaS}} \approx 2.31$ Å and $r_{\text{GeS}} \approx 2.21$ Å [30]. Similar observations were made for the Ga and Ge coordination environments for glasses in the La2S3–Er2S3–Ga2S3–GeS2 system from other EXAFS investigations at the Ga and Ge K-edges in which the ratio of Ga2S3 to GeS2 was varied [31]. In the case of glassy (R2Si)0.25(GaS3)0.417(GeS2)0.333 (R = La or Ce), EXAFS investigations at the $L_{\text{III}}$-edge gave a coordination number $n_{\text{La}}^S \approx 10.5$ with a bond distance $r_{\text{LaS}} \approx 2.99$ Å or a coordination number $n_{\text{Ce}}^S \approx 7.6$ with a bond distance $r_{\text{CeS}} \approx 2.96$ Å [30]. In comparison, EXAFS investigations of glasses in the La2S3–Ga2S3 system at the Ga K-edge and La $L_{\text{III}}$-edge indicate a network based on corner-sharing GaS4 tetrahedra with a bond distance $r_{\text{GaS}} \approx 2.26–2.27$ Å, and a coordination number $n_{\text{La}}^S \approx 7$ with a bond distance $r_{\text{LaS}} = 2.91–2.93$ Å [99].

- Raman spectroscopy was used to measure the structure of glassy (La2S3)x(Ga2S3)y(GeS2)z (1−x−y) with 0 ≤ x ≤ 0.35 [7].
is compensated by the formation of Ga–S and Ge–S homopolar bonds, which for the electronegativity difference between the atomic species is greater. Edge-sharing tetrahedral connections are allowed, especially in respect of Ga centered units. The negative charge on units such as GaS$_4^-$ is compensated by the positive charge on units such as (S$_3$Ge$\cdot$S$\cdot$S$_3$)$^2^-$, where these charges are calculated on the basis of bridging S atoms. When La$_2$S$_3$ is introduced, the provision of additional S atoms breaks homopolar bonds to enable all of the Ge and Ga atoms to form corner-sharing GaS$_4$ or GeS$_4$ tetrahedra in which some of the S atoms are non-bridging. In addition, edge-sharing tetrahedra are converted to corner-sharing tetrahedra, and the resultant motifs may also contain non-bridging S atoms. Hence, negatively charged tetrahedral units are formed that can balance the positive charge on the added La$^{3+}$ ions.

The present neutron and x-ray diffraction work on the structure of glassy (R$_2$S)$_{0.07}$(Ga$_2$S$_3$)$_{0.33}$(GeS$_2$)$_{0.60}$, where the composition can be re-written as (R$_2$S)$_{0.07}$(Ga$_2$S$_3$)$_{0.3548}$(GeS$_2$)$_{0.6452}$. It is consistent with the formation of GaS$_4$ and GeS$_4$ tetrahedra as network forming motifs. By contrast, in the crystalline structures of R–Ga–Ge–S, R–Ga–S and R–Ge–S materials with R = La or Ce, the Ga and Ge atoms can form either tetrahedral or octahedral motifs with S atoms, depending on the composition (table 3). The first peak in the measured $G_N(r)$ functions (figure 4) has a small high-r shoulder at $\approx$2.55 Å, a distance that is longer than typical intra-tetrahedral Ga–S and Ge–S distances (table 3). It may therefore originate from the longer bond lengths found in higher coordinated Ge or Ga centred polyhedra, or from Ga–Ga homopolar bonds, where the Ga–Ga nearest-neighbour distance is 2.45 Å in crystalline GaS$_2$[10], 2.43–2.48 Å in crystalline GaSe [101], or 2.48–2.69 Å in the different polymorphs of crystalline Ga$_2$[102–105]. A shoulder at $\approx$2.55 Å does not, however, manifest itself as a notable feature in $G_N(r)$ (figure 6), i.e. this feature in $G_N(r)$ may have a contribution from Fourier transform artifacts. The coordination number $n_S^\delta$ = 8.0(2) found from the measured $\Delta G_{\delta}(r)$ functions for glassy (R$_2$S)$_{0.07}$(Ga$_2$S$_3$)$_{0.33}$(GeS$_2$)$_{0.60}$ (table 2) compares to $n_S^\delta$ = 8–9 for large rare earth ions in related crystalline materials (table 3).

For glassy (R$_2$S)$_{0.07}$(Ga$_2$S$_3$)$_{0.33}$(GeS$_2$)$_{0.60}$, a nearest-neighbour R–R distance of $\approx$4.65 Å, as estimated from the position of the third peak in $\Delta G_R(r)$ (table 2), compares to a minimum nearest-neighbour R–R distance $r_{RR}^m$ =4.02–4.87 Å in crystalline R–Ga–Ge–S, R–Ga–S and R–Ge–S materials with R = La or Ce (table 3). In these crystalline materials,
or and (b) functions shown in figure 10, the results for the Ga

2Se3)0.07(Ga2Se3)0.33(GeSe2)0.60, a

substitution. X-ray diffraction was also employed to measure the structure of the sulphide glass. The experiments on both the sulphide and selenide glasses reveal structures that are based on networks built from GaX4 and GeX4 tetrahedra in which the rare-earth ions reside with an R-X coordination number \( n_R^S = 8.0(2) \) or \( n_R^Se = 8.5(4) \). The results for the Ga and Ge centered network-forming motifs are consistent with the findings from spectroscopic investigations of glasses in the \( R_2S_3-GaS_3-GeS_2 \) system, and show that these conformations are also present in glasses from the \( R_2Se_3-GaSe_3-GeSe_2 \) system. For sulphide and selenide glasses in which rare-earth clustering occurs, representative minimum nearest-neighbour \( R-R \) distances are likely to be 4.0–4.9 Å and 4.5–4.8 Å, respectively, and correspond to \( R-X-R \) connections.

Acknowledgments

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Figure 9. The difference functions (a) \( \Delta F_R^{(1)}(Q) \) and (b) \( \Delta F_R^{(1)}(Q) \) for glassy \((R_2Se_3)_{0.07}(Ga_2Se_3)_{0.33}(GeSe_2)_{0.60}\). The vertical (dark grey) bars represent the measured data points with statistical errors. The solid (red) curves are the back Fourier transforms of the corresponding \( \Delta G_R^{(1)}(r) \) and \( \Delta G_R^{(1)}(r) \) functions shown in figure 10, after the unphysical low-\( r \) oscillations are set to the theoretical \( \Delta G_R^{(1)}(r \to 0) \) or \( \Delta G_R^{(1)}(r \to 0) \) limit.

Figure 10. The difference functions (a) \( \Delta G_R^{(1)}(r) \) and (b) \( \Delta G_R^{(1)}(r) \) for glassy \((R_2Se_3)_{0.07}(Ga_2Se_3)_{0.33}(GeSe_2)_{0.60}\) as obtained by Fourier transforming the corresponding \( \Delta F_R^{(1)}(Q) \) and \( \Delta F_R^{(1)}(Q) \) functions shown in figure 9 after spline fitting the data and applying a cosine window function over the range 7.5–10 Å\(^{-1}\) for \( \Delta G_R^{(1)}(r) \) or 18–23 Å\(^{-1}\) for \( \Delta G_R^{(1)}(r) \). The broken (red) curves indicate the extent of the unphysical low-\( r \) oscillations.

6. Conclusions

The structure of \((R_4X_3)_{0.07}(Ga_2X_3)_{0.33}(GeX_2)_{0.60}\) glasses, where \( R \) denotes La or Ce and \( X \) denotes S or Se, was investigated by using the method of neutron diffraction with isomorphic substitution. X-ray diffraction was also employed to measure the structure of the sulphide glass. The experiments on both the sulphide and selenide glasses reveal structures that are based on networks built from GaX4 and GeX4 tetrahedra in which the rare-earth ions reside with an R-X coordination number \( n_R^S = 8.0(2) \) or \( n_R^Se = 8.5(4) \). The results for the Ga and Ge centered network-forming motifs are consistent with the findings from spectroscopic investigations of glasses in the \( R_2S_3-GaS_3-GeS_2 \) system, and show that these conformations are also present in glasses from the \( R_2Se_3-GaSe_3-GeSe_2 \) system. For sulphide and selenide glasses in which rare-earth clustering occurs, representative minimum nearest-neighbour \( R-R \) distances are likely to be 4.0–4.9 Å and 4.5–4.8 Å, respectively, and correspond to \( R-X-R \) connections.

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